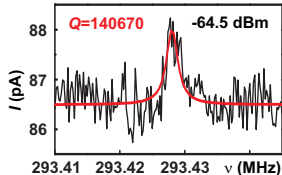
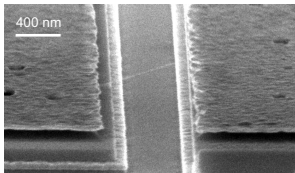
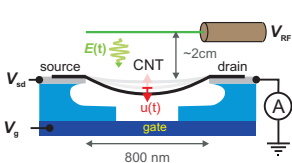
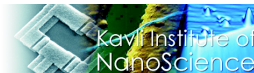


Carbon nanotubes as ultrahigh-Q electromechanical resonators — and (much) more

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Tarucha-Oiwa Laboratory, University of Tokyo, 7 August 2009

Mechanical properties of carbon nanotubes

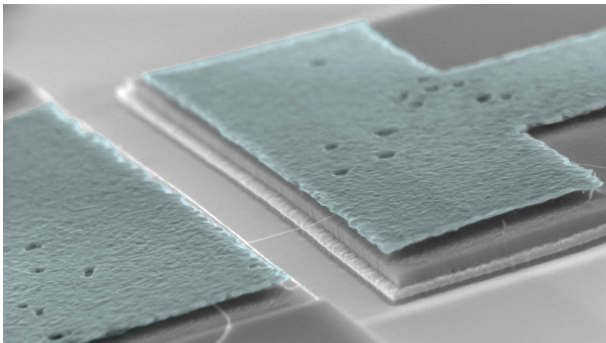
- stiffer than steel
- resistant to damage from physical forces
- very light

- Young's modulus $E = \frac{F/A}{\Delta L/L}$:
 $E_{\text{CNT}} \simeq 1.2 \text{TPa}$, $E_{\text{steel}} \simeq 0.2 \text{TPa}$
- Density:
 $\rho_{\text{CNT}} \simeq 1.3 \frac{\text{g}}{\text{cm}^3}$, $\rho_{\text{Al}} \simeq 2.7 \frac{\text{g}}{\text{cm}^3}$

- (still) “material of dreams”

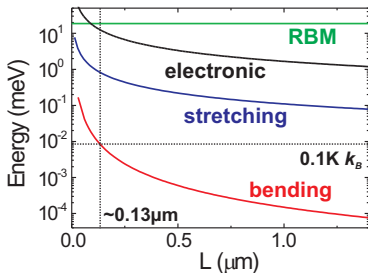


Doubly clamped nanotube resonators



nanotube is suspended like a guitar or violin string
low mass, high stiffness \rightarrow high resonance frequency, large quantum effects
single clean macromolecule \rightarrow low dissipation???

Vibration modes of carbon nanotubes



- **stretching** (longitudinal) mode:

$$h\nu \propto L^{-1}$$

$$h\nu = 1100 \dots 110 \mu\text{eV},$$

$$\nu = 270 \dots 27 \text{GHz}$$

(for 100nm ... 1 μm)

- **bending** (transversal) mode:

$$\hbar\omega \propto L^{-2}$$

$$h\nu = 10 \dots 0.1 \mu\text{eV},$$

$$\nu = 2.4 \text{GHz} \dots 24 \text{MHz}$$

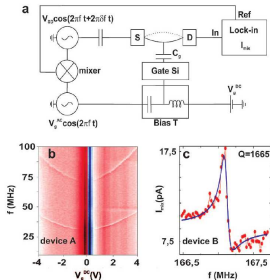
(for 100nm ... 1 μm)

$\hbar\omega \propto d$, also tension-dependent

purely electronic excitations (quantum-mechanical “box potential” for the electrons) have different energy scale

Nanotubes as transversal beam resonators — up to now

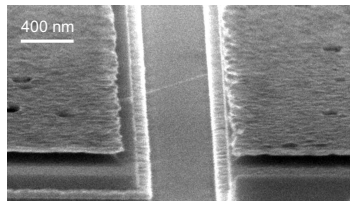
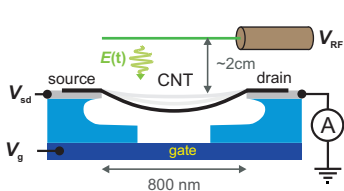
complicated setup — even at 1K, maximally $Q \simeq 2000$



Ultrasensitive Mass Sensing with a Nanotube Electromech. Resonator
B. Lassagne, D. Garcia-Sanchez, A. Aguiasca and A. Bachtold
Nano Lett., 2008, 8 (11), pp 3735–373

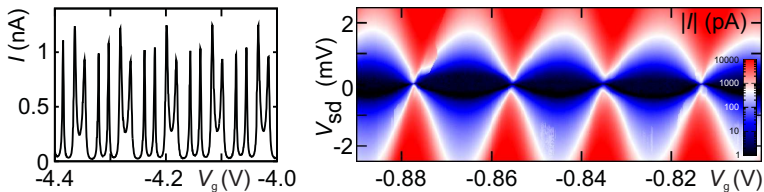
- **Bending** (transversal) vibration mode
- Nanotube as nonlinear circuit element
- RF downmixing at mech. resonance
- $Q \lesssim 2000$ — why?
- HF cables to sample: **heating**, noise
- Contamination during lithography
- Clamping points?

Our chip fabrication and measurement setup

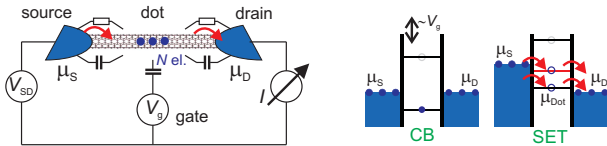


- Nanotube CVD-grown above Pt electrodes, across pre-defined trench
- Back gate connected to a gate voltage source V_g
- RF antenna suspended ~ 2 cm above chip
- Dilution refrigerator ($T \simeq 20$ mK)
- **Only dc measurement**

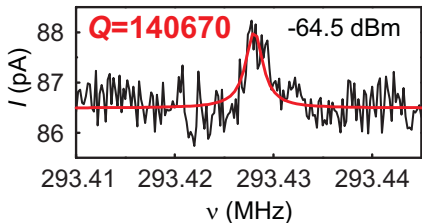
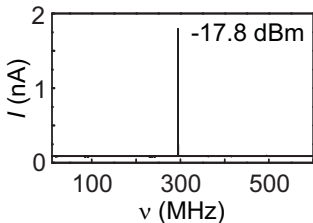
dc Coulomb blockade measurement — beautiful diamonds



highly regular quantum dot within the nanotube

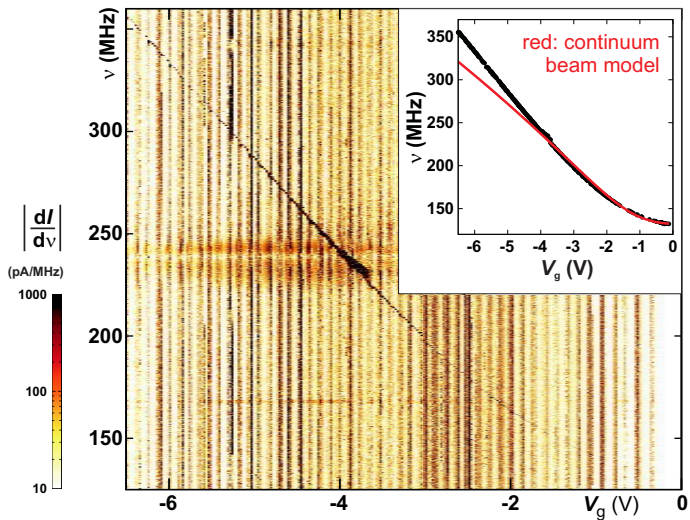


Fixed V_g and V_{SD} , sweep of RF signal frequency



- Sharp resonant structure in $I_{dc}(\nu)$
- Very low driving power required
- From FWHM, $Q \simeq 140000$

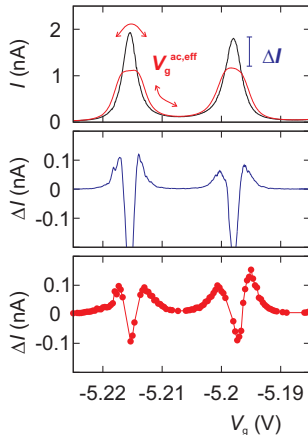
V_g dependence — this is really a mechanical resonance!



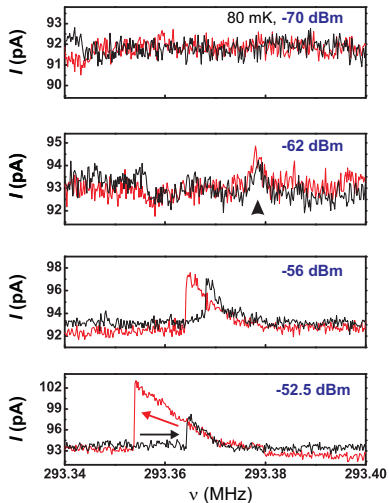
larger $|V_g|$ \longrightarrow increased tension \longrightarrow higher frequency ν

Detection mechanism — mechanically induced averaging

- at resonant driving the nanotube position oscillates
- oscillating C_g
→ fast averaging over $I(V_g)$
- black line: dc measurement $I(V_g)$
- red line: this numerically averaged
- blue: difference, effect of averaging
- red points: measured peak amplitude in $I(v)$, for different values of V_g

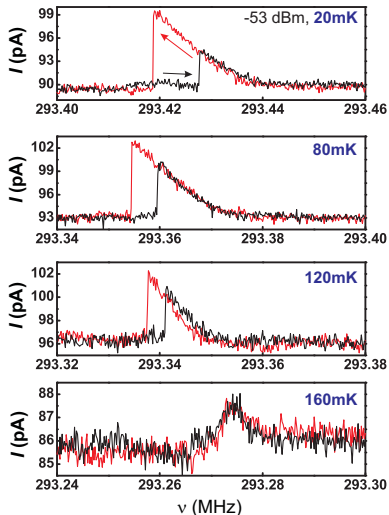


Driving into nonlinear response...



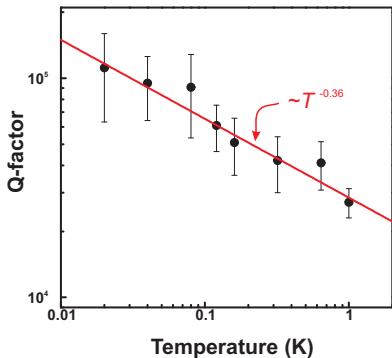
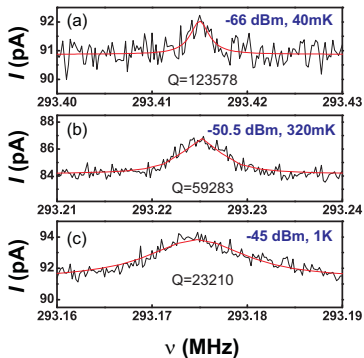
- same temperature
- same working point V_g, V_{SD}
- low driving power:
symmetric, “linear” response
- high driving power:
asymmetric response, hysteresis
Duffing-like oscillator

... and then increasing the temperature



- same driving power
- same working point V_G, V_{SD}
- low temperature:
asymmetric response, hysteresis
Duffing-like oscillator
- high temperature:
symmetric, "linear" response
peak broadening

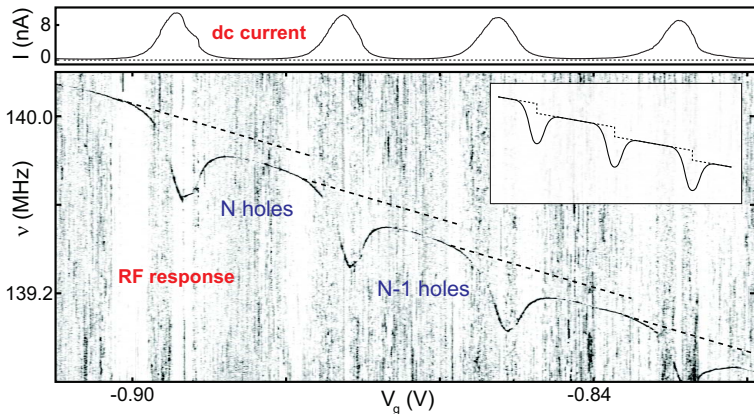
Temperature dependence of Q



$Q(T)$ fits power law prediction for intrinsic dissipation in nanotube

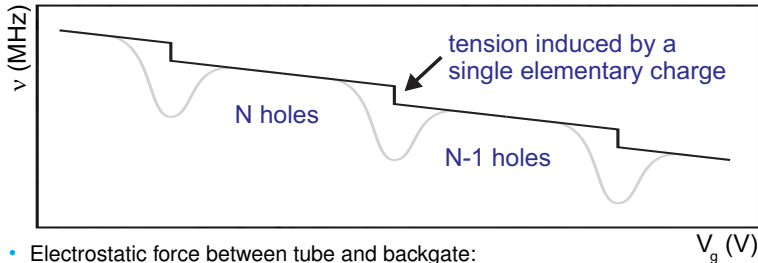
→ H. Jiang *et al.*, Phys. Rev. Lett. **93**, 185501 (2004)

Detailed $\nu(V_g)$: in SET, frequency decreases



“Coulomb blockade oscillations of **mechanical resonance frequency**”
electrostatic contribution to spring constant

Model for $\nu(V_g)$ – part I: “slope and steps”



- Electrostatic force between tube and backgate:

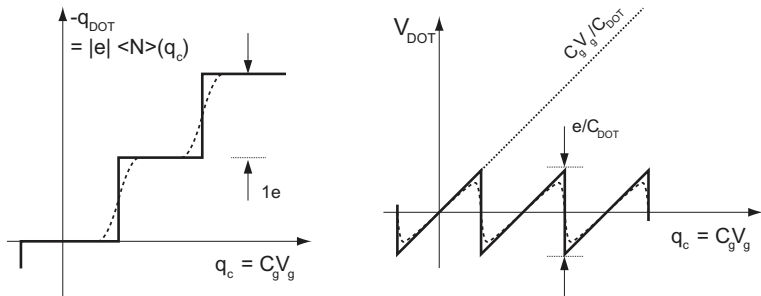
$$F_{\text{dot}} = \frac{1}{2} \frac{dC_g}{dz} (V_g - V_{\text{dot}})^2$$

- Quantum dot voltage:

$$V_{\text{dot}} = \frac{C_g V_g + q_{\text{dot}}}{C_{\text{dot}}}, \quad q_{\text{dot}}(q_c) = -|e| \langle N \rangle (q_c), \quad q_c = C_g V_g$$

- Overall slope: continuous increase of voltage V_g on gate
- Steps: discrete change of V_{dot} (single elementary charges!)

Model for $v(V_g)$ – part II: “steps become dips”

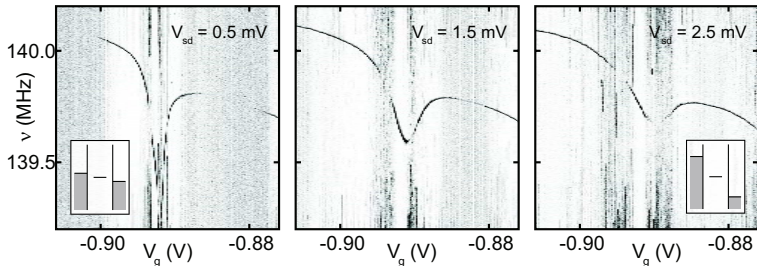


- $q_c = C_g(z) V_g$ is function of z
- Electrostatic contribution to spring constant:

$$k_{\text{dot}} = -\frac{dF_{\text{dot}}}{dz} = \frac{V_g(V_g - V_{\text{dot}})}{C_{\text{dot}}} \left(\frac{dC_g}{dz} \right)^2 \left(1 - |e| \frac{d\langle N \rangle}{dq_c} \right) \quad (1)$$

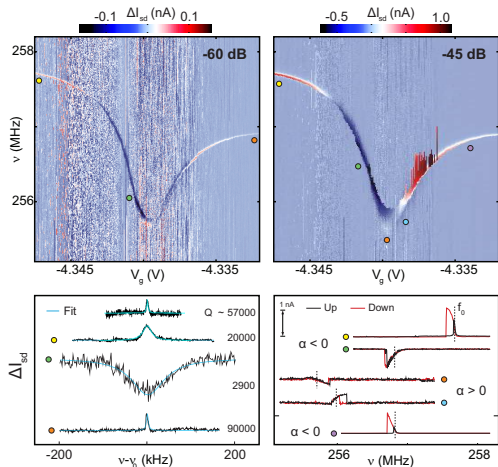
- Always negative, always decreasing frequency

Consistency check: $\nu(V_g)$ and $\frac{d\langle N \rangle}{dq_c}(V_g)$ for higher V_{sd}



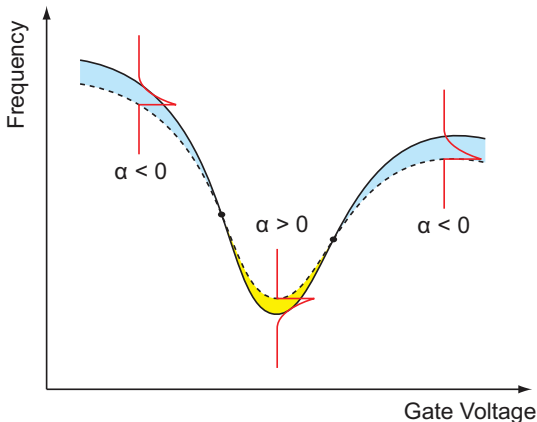
At high V_{sd} , the occupation $\langle N \rangle$ changes over a larger V_g voltage range.
→ wider, shallower dips

Also Q and nonlinearity dominated by interaction



- Dissipation whenever charge can fluctuate
- Q decreases on SET peaks
- Nonlinearity dominated by tunneling
- Switches between weakening and softening spring

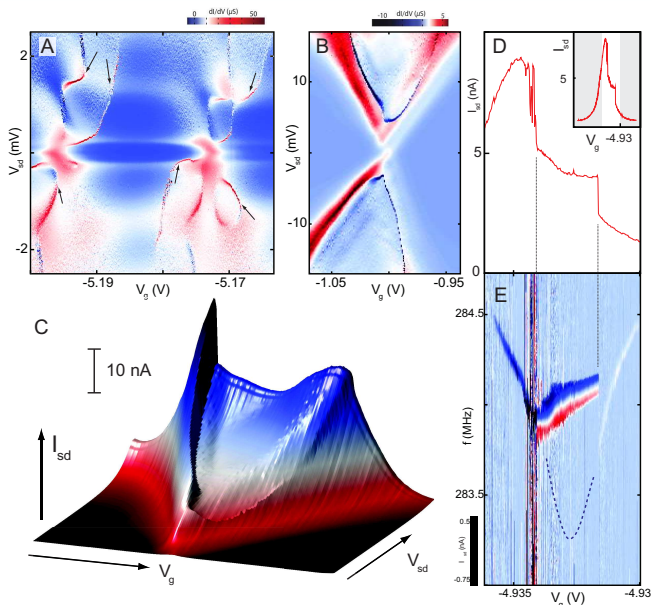
Interaction-induced nonlinearity $\alpha(V_g)$



$$\alpha_{\text{dot}} = -\frac{d^3 F}{dz^3} = \frac{d^2}{dz^2} k_{\text{dot}}(q_c) = V_g^2 \left(\frac{dC_g}{dz} \right)^2 \frac{d^2 k_{\text{dot}}}{dq_c^2} \quad (2)$$

The sign of α_{dot} follows the sign of the curvature of k_{dot} .

Self-excitation of the resonator



Bending mode — summary & outlook!

- $120\text{ MHz} \lesssim \nu \lesssim 360\text{ MHz}$, $Q \lesssim 150000$
- Self-detection of motion via dc current
- Easy driving into nonlinear oscillator regime
- $Q(T)$ is consistent with intrinsic dissipation model
- Single-electron steps of the resonance frequency
- Backaction of single electron tunneling on ν , Q , nonlinearity
- **Self-excitation of motion!**

- Estimated motion amplitude at resonant driving $\sim 250\text{ pm}$
compare thermal motion 6.5 pm , zero-point motion 1.9 pm
- Application as mass sensor: **sensitivity $4.2 \frac{u}{\sqrt{\text{Hz}}}$**
- Without driving: **mechanical thermal occupation $n \simeq 1.2$**

- Stay tuned for more interesting results!!

The team at TU Delft & friends

Thanks!



Gary Steele



Benoit Witkamp



Menno Poot



Leo Kouwenhoven



Harold Meerwaldt



Martin Leijnse



Maarten Wegewijs



Herre van der Zant

Regensburg is a nice place, too.

Questions?

